

## R-C Thermal Model Parameters

### DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

### R-C THERMAL MODEL FOR TANK CONFIGURATION



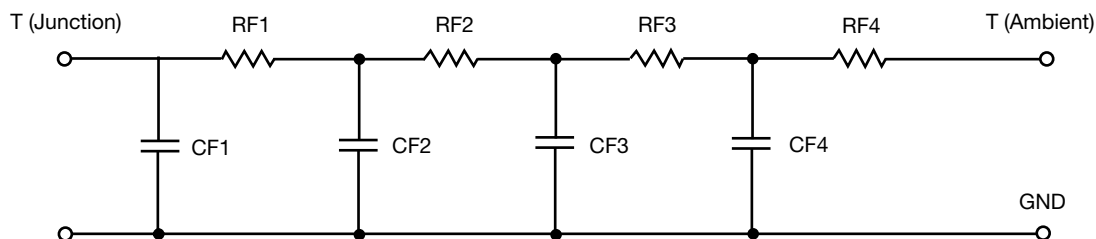
R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	7.7216	10.4338 m	N/A
RT2	13.9406	1.0604	N/A
RT3	5.4544	1.2916	N/A
RT4	57.4794	337.6106 m	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	19.5135 m	3.2949 u	N/A
CT2	125.5090 m	14.2291 m	N/A
CT3	1.2731 m	121.8046 m	N/A
CT4	1.1927	5.2986 m	N/A

#### Note

N/A indicates not applicable

*This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.*

**R-C THERMAL MODEL FOR FILTER CONFIGURATION**



<b>R-C VALUES FOR FILTER CONFIGURATION</b>			
<b>THERMAL RESISTANCE (°C/W)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
RF1	7.2199	74.8235 m	N/A
RF2	14.8045	681.7873 m	N/A
RF3	18.2829	855.4877 m	N/A
RF4	44.5589	1.0724	N/A
<b>THERMAL CAPACITANCE (Joules/°C)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
CF1	1.2613 m	876.8995 u	N/A
CF2	28.7179 m	4.2719 m	N/A
CF3	437.2504 m	8.9976 m	N/A
CF4	1.1212	123.1443 m	N/A

**Note**

N/A indicates not applicable

